

## 2N4991 Integrated Circuit Silicon Bilateral Switch (SBS) TO-92/TO-98 Type Package

### **Description:**

The 2N4991 is a silicon planer, monolithic integrated circuit having the electrical characteristics of a bilateral thyristor. This device is designed to switch at 8 volts with a 0.02%/°C temperature coefficient and excellently matched characteristics in both directions. A gate lead is provided to eliminate rate effect and to obtain triggering at lower voltages.

The 2N4991 is specifically designed and characterized for applications where stability of switching voltage over a wide temperature range and well matched bilateral characteristics are an asset. It is ideally suited for half wave and full wave triggering in low voltage SCR and TRIAC phase control circuits.

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Note 1. Derate linearly to zero at +125°C.

Note 2. This rating applicable only on OFF state. Maximum gate current in conducting state limited by maximum power rating.

Storage Temperature Range, T<sub>stq</sub> ......–65° to +150°C

#### **<u>Electrical Characteristics:</u>** (T<sub>A</sub> = +25°C, Note 3 unless otherwise specified)

Parameter	Symbol	Test Conditions		Min	Тур	Max	Unit
ON State Forward Voltage Drop	V <sub>F</sub>	I <sub>F</sub> = 175mA		_	_	1.7	V
Switching Voltage	V <sub>S</sub>			6	-	10	V
OFF State Forward Current	Ι <sub>Β</sub>	V <sub>F</sub> = 5V	$T_A = +25^{\circ}C$	_	-	1	μΑ
			$T_A = +85^{\circ}C$	_	-	10	μΑ
Switching Current	I <sub>S</sub>		-	_	-	500	μΑ
Absolute Switching Voltage Difference	$ V_{S2} - V_{S1} $			_	_	0.5	V
Absolute Switching Current Difference	I <sub>S2</sub> – I <sub>S1</sub>			_	_	100	μΑ
Holding Current	lΗ			_	_	1.5	mA
Temperature Coefficient of Switching Voltage	T <sub>C</sub>	$T_A = -55^{\circ} \text{ to } +85^{\circ}\text{C}$		_	±0.02	-	%/°C

Note 3. This device is a symmetrical negative resistance diode. All electrical limits shown above apply in either direction of current flow.

# <u>Electrical Characteristics (Cont'd)</u>: $(T_A = +25^{\circ}C, \text{ Note 3 unless otherwise specified})$

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Turn-On Time	t <sub>on</sub>		-	-	1	μS
Turn-Off Time	t <sub>off</sub>		-	_	30	μS
Peak Pulse Amplitude	V <sub>o</sub>		3.5	-	_	V

Note 3. This device is a symmetrical negative resistance diode. All electrical limits shown above apply in either direction of current flow.

